

In the Specification:

Please amend the specification as follows:

Page 6, after the second paragraph insert:

The boron concentration may be less than $5 \times 10^{14} \text{ cm}^{-3}$ and the concentration of transition metals impurities less than $5 \times 10^{14} \text{ cm}^{-3}$. The boron concentration may be less than $5 \times 10^{15} \text{ cm}^{-3}$ and the concentration of transition metals impurities less than 10^{13} . The crystal, after growth, may be annealed to above 700°C .